

View Online at <https://aerobasegroup.com/nsn/5961-01-630-7327>

Inclosure Material:

Ceramic

Overall Length:

20.30 millimeters

End Application:

Advanced hawkeye

Mounting Facility Quantity:

1

Mounting Method:

Unthreaded hole

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

20.0 gate to source voltage

Current Rating Per Characteristic:

50.0 amperes drain current

Power Rating Per Characteristic:

300.0 watts total power dissipation

Product Name:

Transistor, mosfet

Terminal Type And Quantity:

3 solder stud

Shelf Life:

N/a

Unit Of Measure:

--

Demilitarization:

No

Fig:

A110a0